

Data Sheet January 2002

6A, 200V Ultrafast Diodes

The RURD620, and RURD620S are ultrafast diodes with soft recovery characteristics (t_{rr} < 25ns). They have low forward voltage drop and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, reducing power loss in the switching transistors.

Formerly developmental type TA49037.

Ordering Information

PART NUMBER	PACKAGE	BRAND	
RURD620	TO-251	RUR620	
RURD620S	TO-252	RUR620	

NOTE: When ordering, use the entire part number. Add the suffix, 9A, to obtain the TO-252 variant in tape and reel, i.e., RURD620S9A.

Symbol



Features

Ultrafast with Soft Recovery	<25ns
Operating Temperature	175 ⁰ C
Reverse Voltage	.200V
	Operating Temperature

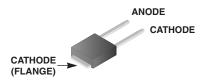
- · Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC STYLE TO-251



JEDEC STYLE TO-252



Absolute Maximum Ratings T_C = 25°C Unless Otherwise Specified

	RURD620 RURD620S	UNITS
Peak Repetitive Reverse Voltage	200	V
Working Peak Reverse Voltage	200	V
DC Blocking VoltageV _R	200	V
Average Rectified Forward Current $I_{F(AV)}$ $T_C = 160^{\circ}C$	6	Α
Repetitive Peak Surge CurrentI _{FRM} Square Wave, 20kHz	12	Α
Nonrepetitive Peak Surge Current	60	Α
Maximum Power Dissipation	45	W
Avalanche Energy (See Figures 10 and 11)	10	mJ
Operating and Storage Temperature	-65 to 175	oC
Maximum Lead Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s	300	300°C
Package Body for 10s, See Tech Brief 334TPKG	260	260°C

Electrical Specifications

 $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 6A	-	-	1.0	V
	I _F = 6A, T _C = 150°C	-	-	0.83	V
I _R	V _R = 200V	-	-	100	μА
	$V_R = 200V, T_C = 150^{\circ}C$	-	-	500	μА
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	25	ns
	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	-	30	ns
t _a	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	13	-	ns
t _b	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	6.5	-	ns
Q _{RR}	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	20	-	nC
CJ	V _R = 10V, I _F = 0A	-	30	-	pF
$R_{ heta JC}$		-	-	3.5	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

 C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

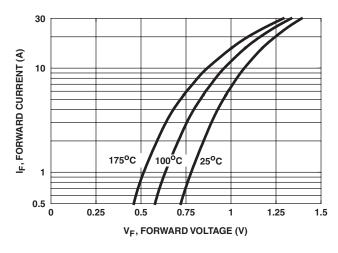


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

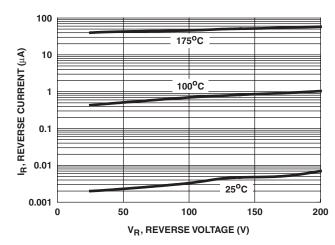


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

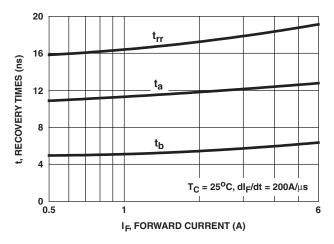


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

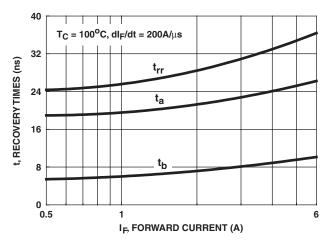


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

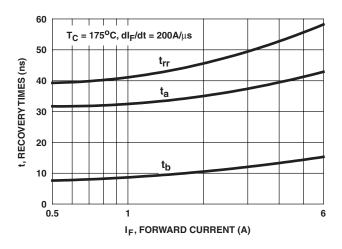


FIGURE 5. t_{rr} , t_a and t_b curves vs forward current

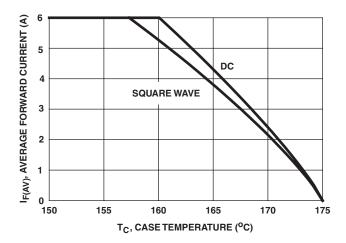


FIGURE 6. CURRENT DERATING CURVE

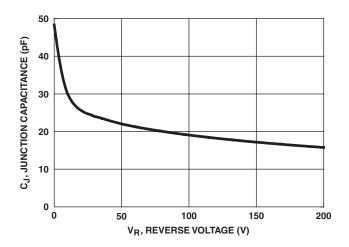


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

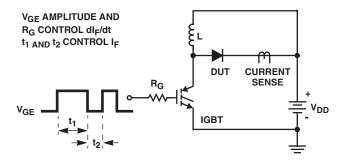


FIGURE 8. t_{rr} TEST CIRCUIT

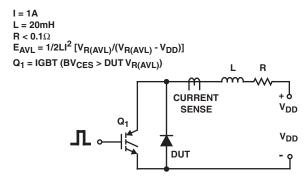


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

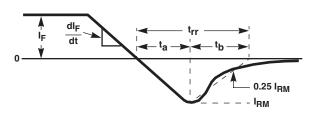


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

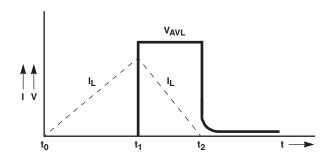


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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